

**APJ ABDULKALAM TECHNOLOGICAL UNIVERSITY
08 PALAKKAD CLUSTER**

6251(A)-17Dec-1

(Pages:2)

Name : _____

Reg.No: _____

FIRST SEMESTER M.TECH. DEGREE EXAMINATION DECEMBER 2017

Branch: Electrical Engineering

Specialization: Power Electronics

08EE6251(A) Power Semiconductor Devices and Modeling

Time:3 hrs

Max. marks: 60

Answer all six questions. Part 'a' of each question is compulsory.

Answer either part 'b' or part 'c' of each question

| | | |
|--------------|-----------------|--------------|
| Q.no. | Module 1 | Marks |
|--------------|-----------------|--------------|

| | | |
|-----|-------------------------------------|---|
| 1.a | What are the three elements of EMC? | 3 |
|-----|-------------------------------------|---|

Answer b or c

| | | |
|---|---|---|
| b | What are the Strategies of Device Selection in Power Electronics? | 6 |
|---|---|---|

| | | |
|---|---|---|
| c | Explain Power Electronic converters and its applications? | 6 |
|---|---|---|

| | | |
|--------------|-----------------|--------------|
| Q.no. | Module 2 | Marks |
|--------------|-----------------|--------------|

| | | |
|-----|--|---|
| 2.a | What makes the power diodes suitable for High Power Applications | 3 |
|-----|--|---|

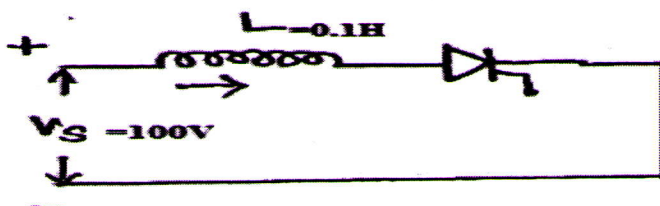
Answer b or c

| | | |
|---|---|---|
| b | Prove that reverse recovery time t_r and Peak Inverse current I_{RM} are dependent on storage charge and rate of change of current? | 6 |
|---|---|---|

| | | |
|---|--|---|
| c | Discuss different types of Power Diodes and its applications | 6 |
|---|--|---|

| | | |
|--------------|-----------------|--------------|
| Q.no. | Module 3 | Marks |
|--------------|-----------------|--------------|

| | | |
|-----|--|---|
| 3.a | The latching current in the circuit shown in fig is 4mA obtain the minimum width of the gating pulse required to properly turn-on the SCR? | 3 |
|-----|--|---|



Answer b or c

